



DMTH6016LPSQ

60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI

Product Summary

BV _{DSS}	Rds(on)	Ι _D T _C = +25°C
60V	16mΩ @ V _{GS} = 10V	37A
	24mΩ @ V _{GS} = 4.5V	29A

Description and Applications

This MOSFET has been designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- **Power Management**
- DC-DC Converters
- Motor Control

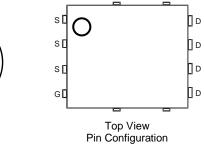
Features

- Rated to +175°C Ideal for High Ambient Temperature **Environments**
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: PowerDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)





Ordering Information (Note 5)

Part Number	Case	Packaging
DMTH6016LPSQ-13	PowerDI5060-8	2,500 / Tape & Reel

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied. Notes:

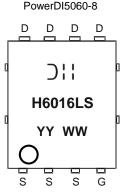
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



DLL = Manufacturer's Marking H6016LS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 16 = 2016) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	60	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current (Note 7) V _{GS} = 10V	T _C = +25°C T _C = +100°C	ID	37 30.3	A
Continuous Drain Current (Note 6) V_{GS} = 10V	$T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$	I _D	9.8 6.9	A
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	75	A	
Maximum Continuous Body Diode Forward Current (Note 7)	Is	31	A	
Avalanche Current, L = 0.1mH	I _{AS}	15.3	A	
Avalanche Energy, L = 0.1mH	Eas	11.7	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	T _A = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 6)		R _{θJA}	57	°C/W
Total Power Dissipation (Note 7)	T _C = +25°C	PD	37.5	W
Thermal Resistance, Junction to Case (Note 7)		R _{θJC}	4	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	•			•			
Drain-Source Breakdown Voltage	BV _{DSS}	60	-	_	V	$V_{GS} = 0V, I_{D} = 250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	—	_	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	—	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)	•		•				
Gate Threshold Voltage	V _{GS(TH)}	1	_	2.5	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		_	12	16	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	21	24	11175	V _{GS} = 4.5V, I _D = 18A	
Diode Forward Voltage	V _{SD}	—	0.7	1.2	V	$V_{GS} = 0V, I_S = 1A$	
DYNAMIC CHARACTERISTICS (Note 9)	•		•				
Input Capacitance	Ciss	_	864	—		$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	—	282	_	pF		
Reverse Transfer Capacitance	Crss	—	27	_			
Gate Resistance	R _G	—	1.3	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	8.4	_			
Total Gate Charge (V _{GS} = 10V)	Qg	—	17	_	nC	$V_{DS} = 30V, I_D = 10A$	
Gate-Source Charge	Q _{gs}	_	3.1	_	nc		
Gate-Drain Charge	Q _{gd}	_	4.3	_			
Turn-On Delay Time	t _{D(ON)}	_	3.4	_		$V_{GS} = 10V, V_{DS} = 30V,$ $R_G = 6\Omega, I_D = 10A$	
Turn-On Rise Time	t _R	_	5.2	_			
Turn-Off Delay Time	t _{D(OFF)}	_	13	_	ns		
Turn-Off Fall Time	t _F	_	7	_			
Reverse Recovery Time	t _{RR}	_	22	_	ns		
Reverse Recovery Charge	Q _{RR}	—	11	—	nC	I _F = 10A, di/dt = 100A/µs	

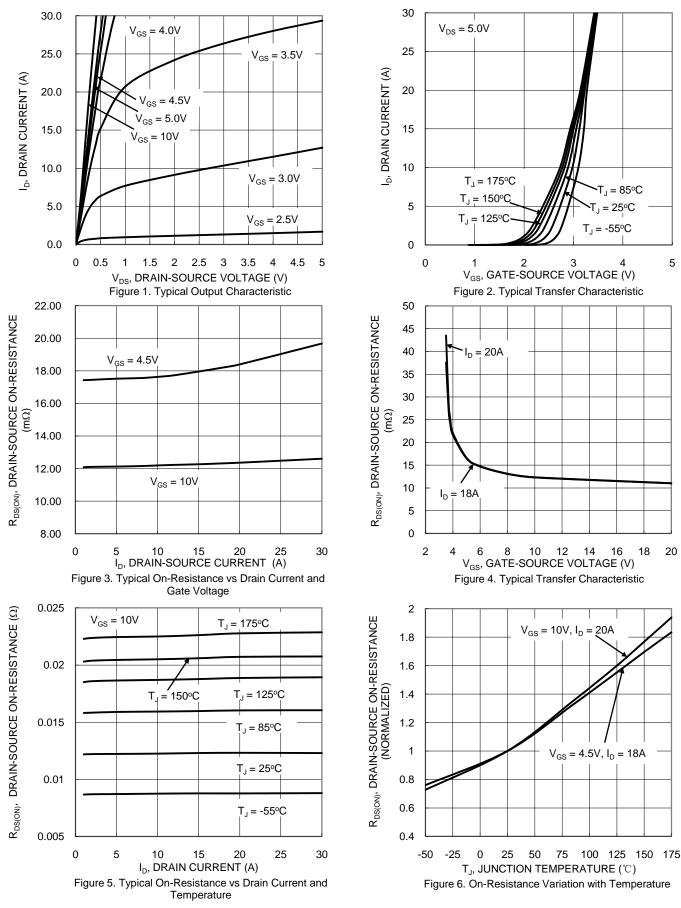
Notes: 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

Thermal resistance from junction to soldering point (on the exposed drain pad).
Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.



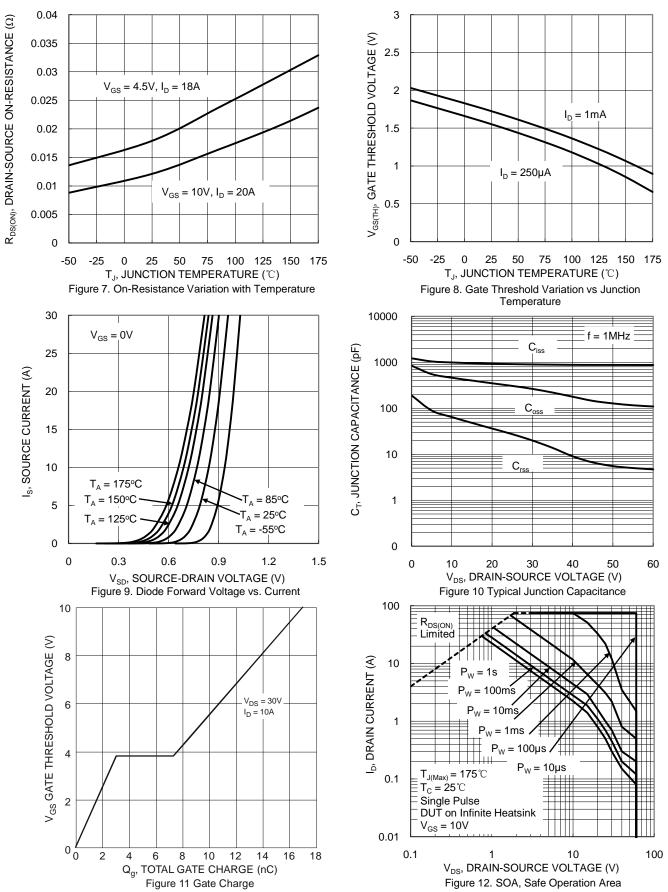
DMTH6016LPSQ



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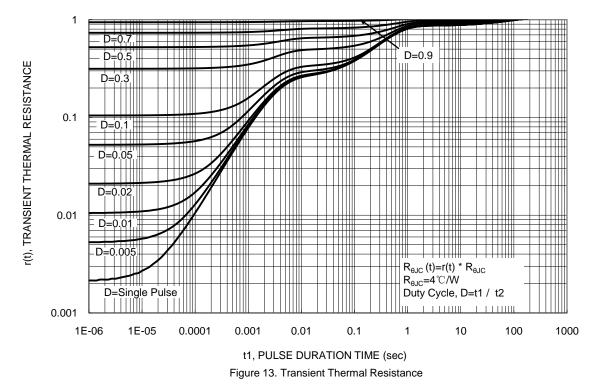
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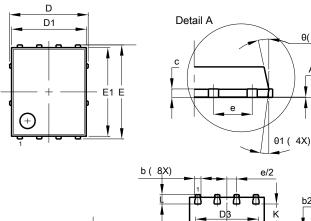
Package Outline Dimensions

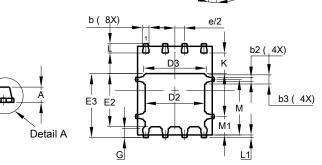
Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

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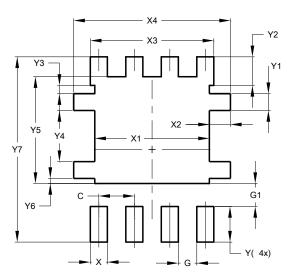


PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
Μ	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12º	11 ⁰		
Θ1	6°	8º	7°		
Al	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	0.755		
X3	4.420		
X4	5.610		
Y	1.270		
Y1	0.600		
Y2	1.020		
Y3	0.295		
Y4	1.825		
Y5	3.810		
Y6	0.180		
Y7	6.610		



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